

CMOS Digital Integrated Circuits Silicon Monolithic

## TC7WZ126FU

#### 1. Functional Description

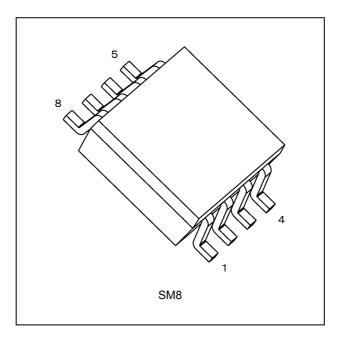
· Dual Bus Buffer with 3-State Output

#### 2. Features

- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High output current:  $\pm 24$  mA (min) at  $V_{CC} = 3.0$  V
- Super high speed operation:  $t_{pd}$  = 2.6 ns (typ.) at  $V_{CC}$  = 5.0 V,  $C_L$  = 50 pF
- Operation voltage range:  $V_{\rm CC}$  = 1.65 to 5.5 V
- (5) 5.5 V tolerant inputs
- (6) 5.5 V power down protection output
- (7) Matches the performance of TC74LCX series when operated at  $3.3~V~V_{\rm CC}$

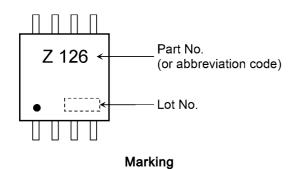
Note 1: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

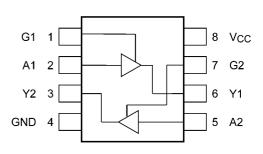
#### 3. Packaging



1

#### 4. Marking and Pin Assignment





Pin Assignment (Top view)

Start of commercial production

2009-09



#### 5. IEC Logic Symbol



#### 6. Truth Table

Input A	Input G	Output Y
Х	L	Z
L	Н	L
Н	Н	Н

X: Don't care

Z: High impedance

#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	$V_{CC}$		-0.5 to 6.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 6.0	٧
DC output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 6.0	٧
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 3)	-20	mA
DC output current	l <sub>out</sub>		±50	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	P <sub>D</sub>		300	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 \text{ V}$  or high impedance condition

Note 2: High (H) or Low (L) state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND



#### 8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		_	1.65 to 5.5	V
		(Note 1)	_	1.5 to 5.5	
Input voltage	V <sub>IN</sub>		_	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	(Note 2)	_	0 to 5.5	V
		(Note 3)	_	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub>	(Note 4)	_	-40 to 125	°C
		(Note 5)	_	-40 to 85	
Input rise and fall time	dt/dv		$V_{CC}$ = 1.8 $\pm$ 0.15 V, 2.5 $\pm$ 0.2 V	0 to 20	ns/V
			$V_{CC} = 3.3 \pm 0.3 \text{ V}$	0 to 10	
			$V_{CC} = 5.0 \pm 0.5 \text{ V}$	0 to 5	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2: V<sub>CC</sub> = 0 V or high impedance condition

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

#### 9.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 1.95	$V_{CC} \times 0.75$	_	_	V
				2.3 to 5.5	V <sub>CC</sub> × 0.70	_	_	
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 1.95	_	_	$V_{CC} \times 0.25$	V
				2.3 to 5.5		_	$V_{CC} \times 0.30$	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> = -100 μA	1.65	1.55	1.65	_	V
				2.3	2.2	2.3	_	
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -4 mA	1.65	1.29	1.52	_	
			I <sub>OH</sub> = -8 mA	2.3	1.9	2.15	_	
			I <sub>OH</sub> = -16 mA	3.0	2.4	2.8	_	
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.68	_	
			I <sub>OH</sub> = -32 mA	4.5	3.8	4.2	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 100 μA	1.65		0.0	0.1	V
				2.3		0.0	0.1	
				3.0	-	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	1.65	ı	0.08	0.24	
			I <sub>OL</sub> = 8 mA	2.3		0.1	0.3	
			I <sub>OL</sub> = 16 mA	3.0		0.15	0.4	
			I <sub>OL</sub> = 24 mA	3.0	ı	0.22	0.55	
			I <sub>OL</sub> = 32 mA	4.5	ı	0.22	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5			±1	μА
3-state output OFF-state leakage current	l <sub>oz</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5			±1	μА
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0	_		1	μΑ
Quiescent supply current	Icc	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5			1	μА



## 9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 1.95	V <sub>CC</sub> × 0.75	_	V
				2.3 to 5.5	V <sub>CC</sub> × 0.70	_	
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 1.95		V <sub>CC</sub> × 0.25	V
				2.3 to 5.5	_	V <sub>CC</sub> × 0.30	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$	I <sub>OH</sub> = -100 μA	1.65	1.55	_	V
				2.3	2.2	_	
				3.0	2.9	_	
				4.5	4.4	_	
			I <sub>OH</sub> = -4 mA	1.65	1.29	_	
			I <sub>OH</sub> = -8 mA	2.3	1.9	_	
			I <sub>OH</sub> = -16 mA	3.0	2.4	_	
			I <sub>OH</sub> = -24 mA	3.0	2.3	_	
			I <sub>OH</sub> = -32 mA	4.5	3.8	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.65	_	0.1	V
				2.3	_	0.1	
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	1.65	_	0.24	
			I <sub>OL</sub> = 8 mA	2.3	_	0.3	
			I <sub>OL</sub> = 16 mA	3.0	_	0.4	
			I <sub>OL</sub> = 24 mA	3.0	_	0.55	
			I <sub>OL</sub> = 32 mA	4.5	_	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±10	μΑ
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5		±10	μА
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0		10	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5	_	10	μΑ



## 9.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Condition	า	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 1.95	$V_{CC} \times 0.75$	_	V
				2.3 to 5.5	$V_{CC} \times 0.70$		
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 1.95		$V_{CC}\times 0.25$	٧
				2.3 to 5.5	ı	$V_{CC}\times 0.30$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$	I <sub>OH</sub> = -100 μA	1.65	1.55		٧
				2.3	2.2	ı	
				3.0	2.9	ı	
				4.5	4.4		
			$I_{OH} = -4 \text{ mA}$	1.65	0.95		
			I <sub>OH</sub> = -8 mA	2.3	1.7		
			I <sub>OH</sub> = -16 mA	3.0	2.2		
			I <sub>OH</sub> = -24 mA	3.0	2.0	_	
			I <sub>OH</sub> = -32 mA	4.5	3.4	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 100 μA	1.65	_	0.1	٧
				2.3		0.1	
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	1.65		0.7	
			I <sub>OL</sub> = 8 mA	2.3	_	0.45	
			I <sub>OL</sub> = 16 mA	3.0	_	0.6	
			I <sub>OL</sub> = 24 mA	3.0	_	8.0	
			I <sub>OL</sub> = 32 mA	4.5	_	8.0	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	•	0 to 5.5	_	±20	μΑ
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_	±20	μА
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0		100	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5	_	100	μΑ

Note: For devices with the ordering part number ending in J(CT.



### 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$R_L = 1 M\Omega$	$1.8 \pm 0.15$	15	2.0	5.3	11.0	ns
			See 9.7.1 AC Test Circuit, Table 9.7.1	2.5 ± 0.2		0.8	3.4	7.5	
			Circuit, Table 9.7.1	$3.3\pm0.3$		0.5	2.5	5.2	
				$5.0 \pm 0.5$		0.5	2.1	4.5	
			$R_L = 500 \Omega$	$3.3\pm0.3$	50	1.5	3.2	5.7	ns
			See 9.7.1 AC Test Circuit, Table 9.7.1	$5.0 \pm 0.5$		0.8	2.6	5.0	
Output enable time	$t_{PZL}, t_{PZH}$		R <sub>L</sub> = 500 Ω	$1.8 \pm 0.15$	50	2.0	7.0	14.9	ns
			See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5\pm0.2$		1.5	4.6	8.5	
			Olicult, Table 9.7.1	$3.3\pm0.3$		1.5	3.5	6.2	
				$5.0\pm0.5$		8.0	2.8	5.5	
Output disable time	$t_{PLZ}, t_{PHZ}$		R <sub>L</sub> = 500 Ω	$1.8 \pm 0.15$	50	2.0	5.4	11.8	ns
			See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5\pm0.2$		1.5	4.0	8.0	
			Olicult, Table 5.7.1	$3.3 \pm 0.3$		1.0	3.5	5.7	
				$5.0 \pm 0.5$		0.5	2.5	4.7	
Input capacitance	C <sub>IN</sub>		_	0 to 5.5	_	_	4		pF
Output capacitance	C <sub>OUT</sub>		_	0 to 5.5		_	4		pF
Power dissipation	C <sub>PD</sub>	(Note 1)	_	3.3	_	_	17	_	pF
capacitance				5.5	_	_	24	_	pF

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per 1 gate)}$ 

# 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit					
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$R_L = 1 M\Omega$	1.8 ± 0.15	15	2.0	11.5	ns					
		See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5\pm0.2$		8.0	8.0						
		Table 9.7.1	$3.3 \pm 0.3$		0.5	5.5						
			$5.0 \pm 0.5$		0.5	4.8						
		$R_L = 500 \Omega$	$3.3 \pm 0.3$	50	1.5	6.0	ns					
		See 9.7.1 AC Test Circuit, Table 9.7.1	5.0 ± 0.5		0.8	5.3						
Output enable time	$t_{PZL}, t_{PZH}$	$R_L = 500 \Omega$	$1.8 \pm 0.15$	50	2.0	16.6	ns					
		See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5 \pm 0.2$		1.5	9.0						
					Table 5.7.1	Table 5.7.1	Table 5.7.1	$3.3 \pm 0.3$		1.5	6.5	
			$5.0 \pm 0.5$		8.0	5.8						
Output disable time	$t_{PLZ}, t_{PHZ}$	R <sub>L</sub> = 500 Ω	1.8 ± 0.15	50	2.0	12.7	ns					
		See 9.7.1 AC Test Circuit,	See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5 \pm 0.2$		1.5	8.5					
		Table 5.7.1	$3.3 \pm 0.3$		1.0	6.0						
			$5.0 \pm 0.5$		0.5	5.0						



# 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit				
Propagation delay time	$t_{PLH}, t_{PHL}$	$R_L = 1 M\Omega$	1.8 ± 0.15	15	2.0	13.0	ns				
		See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5\pm0.2$		0.8	9.0					
		Table 5.7.1	$3.3 \pm 0.3$		0.5	6.5					
			$5.0 \pm 0.5$		0.5	5.5					
		$R_L = 500 \Omega$	$3.3\pm0.3$	50	1.5	7.0	ns				
		See 9.7.1 AC Test Circuit, Table 9.7.1	5.0 ± 0.5		0.8	6.0					
Output enable time	$t_{PZL}, t_{PZH}$	R <sub>L</sub> = 500 Ω	1.8 ± 0.15	50	2.0	18.5	ns				
		See 9.7.1 AC Test Circuit,	,	See 9.7.1 AC Test Circuit, Table 9.7.1	$2.5 \pm 0.2$		1.5	10.0			
						Table 9.7.1	$3.3 \pm 0.3$		1.5	7.5	
			$5.0 \pm 0.5$		0.8	6.5					
Output disable time	$t_{PLZ}, t_{PHZ}$	$R_L = 500 \Omega$	1.8 ± 0.15	50	2.0	14.0	ns				
		See 9.7.1 AC Test Circuit, Fable 9.7.1	$2.5 \pm 0.2$		1.5	9.5					
		Table 5.7.1	$3.3\pm0.3$		1.0	7.0					
			$5.0\pm0.5$		0.5	5.5					

Note: For devices with the ordering part number ending in J(CT.

#### 9.7. AC Test Circuit

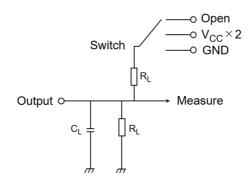


Fig. 9.7.1 AC Test Circuit

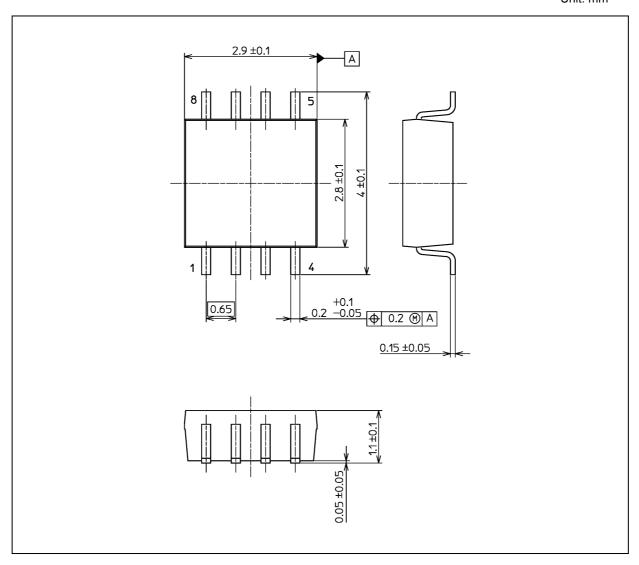
Table 9.7.1 Parameter for AC Test Circuit

Characteristics	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PLZ</sub> , t <sub>PZL</sub>	V <sub>CC</sub> × 2
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND



### **Package Dimensions**

Unit: mm



Weight: 21 mg (typ.)

	Package Name(s)
JEDEC: SOT-505	
Nickname: SM8	



#### **RESTRICTIONS ON PRODUCT USE**

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- · TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's
  written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications.
  TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").
  - Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant.
  - IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.

For details, please contact your TOSHIBA sales representative or contact us via our website.

- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
  FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER,
  INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS,
  INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS
  OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE,
  USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR
  A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
   Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

## **Toshiba Electronic Devices & Storage Corporation**

https://toshiba.semicon-storage.com/